

2SC4421

Silicon NPN Triple-Diffused Planar Type

High Breakdown Voltage, High Speed Switching

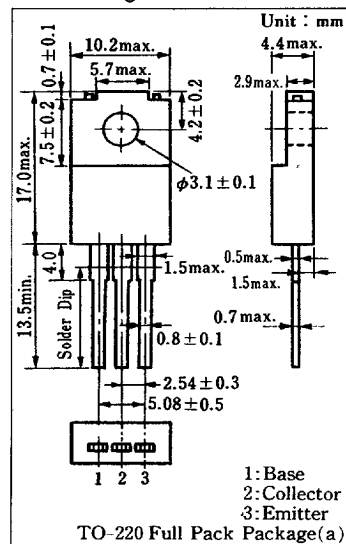
■ Features

- High speed switching
- High collector-base voltage (V_{CBO})
- Wide area of safety operation (ASO)
- Good linearity of DC current gain (h_{FE})
- “Full Pack” package for simplified mounting on a heat sink with one screw

■ Absolute Maximum Ratings (Tc=25°C)

Item		Symbol	Value	Unit
Collector-base voltage		V_{CBO}	500	V
Collector-emitter voltage		V_{CES}	500	V
		V_{CEO}	400	V
Emitter-base voltage		V_{EBO}	7	V
Peak collector current		I_{CP}	6	A
Collector current		I_C	3	A
Base current		I_B	1.2	A
Collector power dissipation	$T_C = 25^\circ\text{C}$	P_C	40	W
	$T_a = 25^\circ\text{C}$		2	
Junction temperature		T_J	150	$^\circ\text{C}$
Storage temperature		T_{stg}	$-55 \sim +150$	$^\circ\text{C}$

■ Package Dimensions



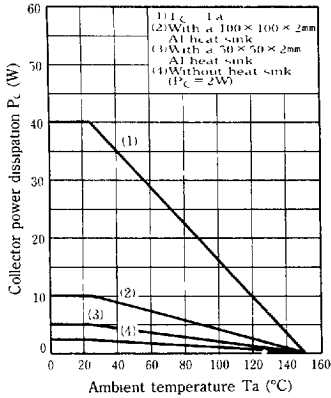
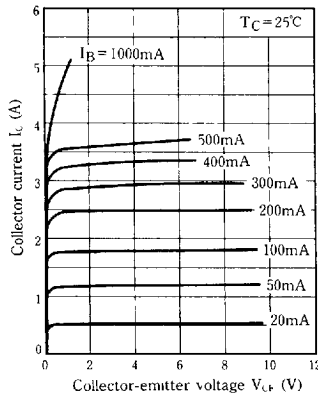
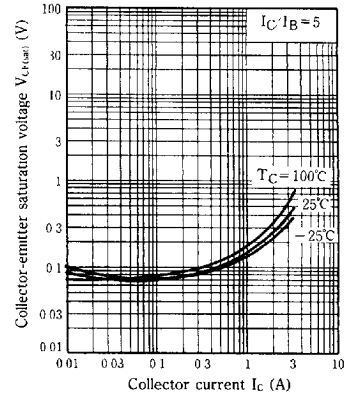
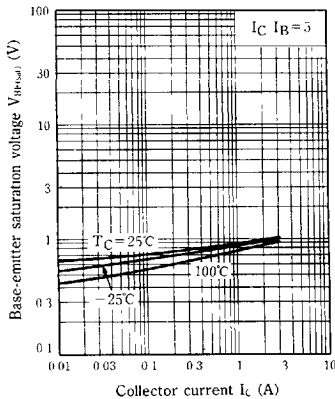
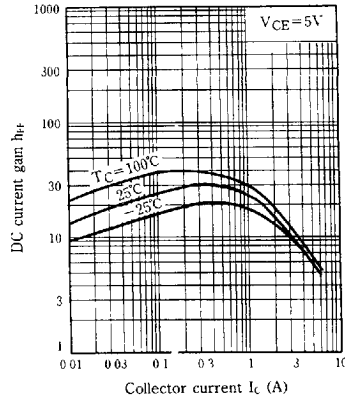
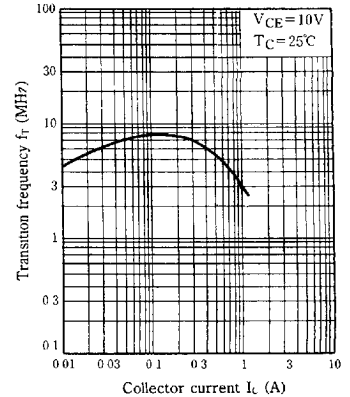
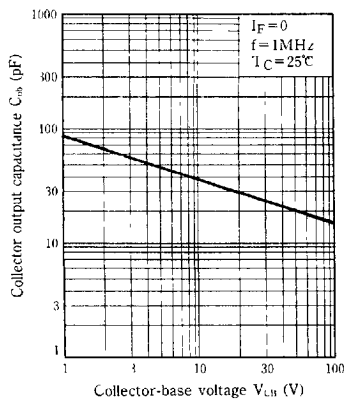
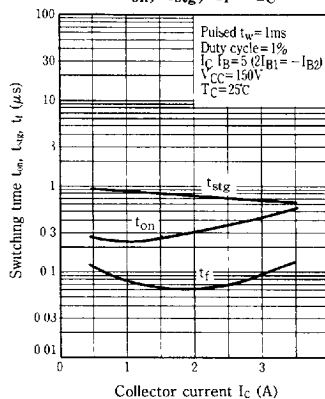
■ Electrical Characteristics (T_c=25°C)

Item	Symbol	Condition	min.	typ.	max.	Unit
Collector cutoff current	I_{CBO}	$V_{CB}=500V, I_E=0$			100	μA
Emitter cutoff current	I_{EBO}	$V_{EB}=5V, I_C=0$			100	μA
Collector-emitter voltage	V_{CEO}	$I_C=10mA, I_B=0$	400			V
DC current gain	h_{FE1}	$V_{CE}=5V, I_C=0.1A$	10			
	h_{FE2}	$V_{CE}=5V, I_C=1.5A$	6			
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=1.5A, I_B=0.3A$			1.5	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C=1.5A, I_B=0.3A$			1.5	V
Transition frequency	f_T	$V_{CE}=10V, I_C=0.2A, f=1MHz$		5		MHz
Turn-on time	t_{on}	$I_C=1.5A$ $I_{B1}=0.3A, I_{B2}=-0.6A$ $V_{CC}=150V$			0.5	μs
Storage time	t_{stg}				2.0	μs
Collector current fall time	t_f				0.1	μs

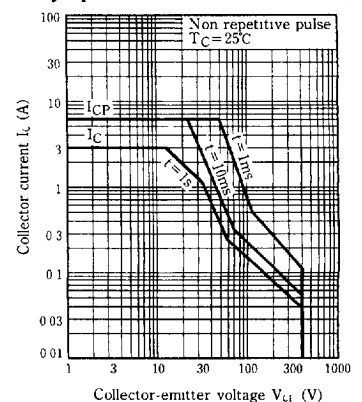
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$P_C - T_a$  $I_C - V_{CE}$  $V_{CE(sat)} - I_C$  $V_{BE(sat)} - I_C$  $h_{FE} - I_C$  $f_T - I_C$  $C_{ob} - V_{CB}$  $t_{on}, t_{stg}, t_f - I_C$ 

Safety operation area-forward bias (ASO)

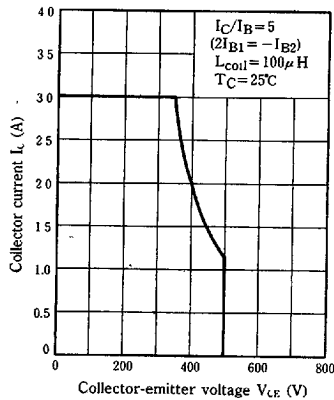


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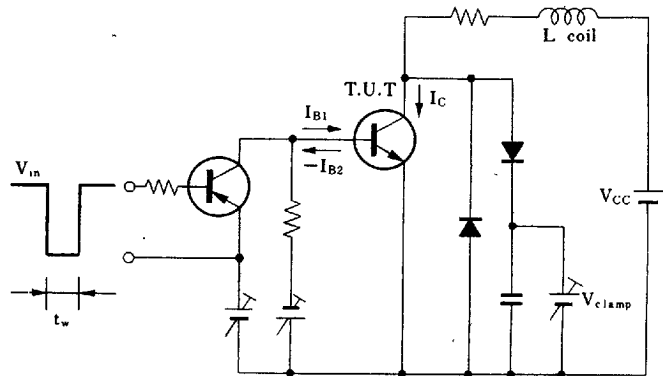
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Safety operation area-reverse bias (ASO)



Measurement circuit of reverse bias ASO

 $R_{th(t)} - t$ 